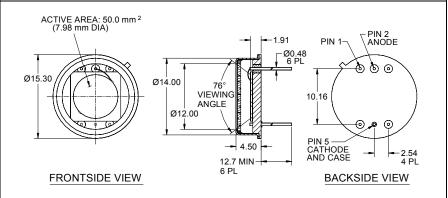


## Pacific Silicon Sensor Series 6 Data Sheet

Part Description PC50-6-TO8 Order # 03-209





#### **FEATURES**

- Ø 7.98 mm active area
- Low dark current
- Long term stability
- · High shunt resistance

# **DESCRIPTION**

50.0 mm<sup>2</sup> Low Dark Current PIN Photodiode. Packaged in a TO-8 with a non-hermetic ultra flat fused silica glass window cap. Also available with six pin isolated case package.

#### **APPLICATIONS**

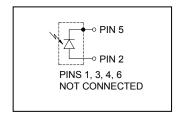
- Precision photometry
- · Bar code readers
- · Medical equipment
- · Pulsed light sensor



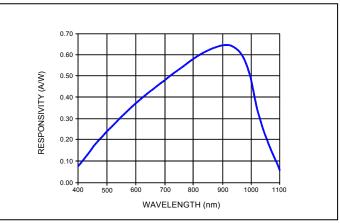
## **ABSOLUTE MAXIMUM RATING**

| SYMBOL              | PARAMETER                 | MIN | MAX | UNITS |  |
|---------------------|---------------------------|-----|-----|-------|--|
| T <sub>STG</sub>    | Storage Temp              | -20 | +80 | °C    |  |
| T <sub>OP</sub>     | Operating Temp            | -20 | +60 | °C    |  |
| $V_{R(OP)}$         | Reverse Operating Voltage | -   | 50  | V     |  |
| I <sub>(PEAK)</sub> | Peak DC Current           | -   | 10  | mA    |  |

#### **SCHEMATIC**



## **SPECTRAL RESPONSE**



# **ELECTRO-OPTICAL CHARACTERISTICS @ 22° C**

| SYMBOL          | CHARACTERISTIC         | TEST CONDITIONS   | MIN | TYP                     | MAX | UNITS               |
|-----------------|------------------------|---|-----|-------------------------|-----|---------------------|
| R <sub>SH</sub> | Shunt Resistance       | $V_R = \pm 10 \text{ mV}$   | 100 | 300                     |     | MΩ                  |
| I <sub>D</sub>  | Dark Current           | V <sub>R</sub> = 10 V   |     | 0.5                     |     | nA                  |
| С               | Capacitance            | $V_R = 0 V;$  |     | 480                     |     | pF                  |
|                 |                        | $V_R = 10 \text{ V};$   |     | 100                     |     |                     |
|                 | Responsivity           | $V_R = 0 \text{ V}; \lambda = 633 \text{ nm}$                         |     | 0.40                    |     | A/W                 |
|                 |                        | $V_R = 0 \text{ V}; \lambda = 900 \text{ nm}$                         |     | 0.64                    |     |                     |
| NEP             | Noise Equivalent Power | $V_R$ = 10 V; $\lambda$ = 850 nm; $R_L$ = 50 $\Omega$                 |     | 2.5 X 10 <sup>-14</sup> |     | W/Hz <sup>1/2</sup> |
| $V_{BR}$        | Breakdown Voltage      | I <sub>R</sub> = 10 μA  | 100 |                         |     | V                   |
| t <sub>r</sub>  | Rise Time              | $V_R = 10 \text{ V}; \ \lambda = 850 \text{ nm}; \ R_L = 50 \ \Omega$ |     | 30                      |     | ns                  |
|                 |                        | $V_R = 80 \text{ V}; \lambda = 850 \text{ nm}; R_L = 50 \Omega$       |     | 7                       |     |                     |

Disclaimer: Due to our policy of continued development, specifications are subject to change without notice.

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First Sensor: PC50-6-TO8